2. RECIPROCAL SPACE IN CRYSTAL-STRUCTURE DETERMINATION

refinement. NQEST identified the best phase solutions. Later *QTAN* was used to evaluate the effect of elastic crystal bend on the structure analysis of cytosine (Moss & Dorset, 1982).

In actual experimental applications, two forms of thiourea were investigated with OTAN (Dorset, 1992d), using published threedimensional electron-diffraction intensities (Dvorvankin & Vainshtein, 1960, 1962). Analysis of the centrosymmetric paraelectric structure yielded results equivalent to those found earlier by symbolic addition (Dorset, 1991b). Analysis of the noncentrosymmetric ferroelectric form was also quite successful (Dorset, 1992d). In both cases, the correct structure was found at the lowest value of NOEST. Re-analysis of the diketopiperazine structure with OTAN also found the correct structure (Dorset & McCourt, 1994a) within the four lowest values of NQEST, but not the one at the lowest value. The effectiveness of this figure of merit became more questionable when QTAN was used to solve the noncentrosymmetric crystal structure of a polymer (Dorset, McCourt, Kopp et al., 1994). The solution could not be found readily when *NOEST* was used but was easily identified when the minimal function $R(\phi)$ was employed instead.

MULTAN has been used to phase simulated data from copper perchlorophthalocyanine (Fan et al., 1985). Within the 2 Å resolution of the electron-microscope image, if one seeks phases for diffraction data in reciprocal-space regions where the objective lens phase contrast transfer function |C(s)| < 0.2, the method proves to be successful. The method is also quite effective for phase extension from 2 Å to 1 Å diffraction resolution, where the lowangle data serve as a large initial phase set for the tangent formula. However, no useful results were found from an ab initio phase determination carried out solely with the electron-diffraction structure-factor magnitudes. Similar results were obtained when RANTAN was used to phase experimental data from this compound (Fan et al., 1991), i.e. the multisolution approach worked well for phase extension but not for ab initio phase determination. Additional tests were subsequently carried out with QTAN on an experimental hk0 electron-diffraction data set collected at 1200 kV (Dorset, McCourt, Fryer et al., 1994). Again, ab initio phase determination is not possible by this technique. However, if a basis set was constructed from the Fourier transform of a 2.4 Å image, a correct solution could be found, but not at the lowest value of NQEST. This figure of merit was useful, however, when the basis set was taken from the symbolic addition determination mentioned in the previous section.

2.5.7.5. Density modification

Another method of phase determination, which is best suited to refining or extending a partial phase set, is the Hoppe–Gassmann density modification procedure (Hoppe & Gassmann, 1968; Gassmann & Zechmeister, 1972; Gassmann, 1976). The procedure is very simple but also very computer-intensive. Starting with a small set of (phased) $F_{\mathbf{h}}$, an initial potential map $\varphi(\mathbf{r})$ is calculated by Fourier transformation. This map is then modified by some realspace function, which restricts peak sizes to a maximum value and removes all negative density regions. The modified map $\varphi'(\mathbf{r})$ is then Fourier-transformed to produce a set of phased structure factors. Phase values are accepted via another modification function in reciprocal space, e.g. $E_{\text{calc}}/E_{\text{obs}} \geq p$, where p is a threshold quantity. The new set is then transformed to obtain a new $\varphi(\mathbf{r})$ and the phase refinement continues iteratively until the phase solution converges (judged by lower crystallographic R values).

The application of density modification procedures to electroncrystallographic problems was assessed by Ishizuka *et al.* (1982), who used simulated data from copper perchlorophthalocyanine within the resolution of the electron-microscope image. The method was useful for finding phase values in reciprocal-space regions where the transfer function $|C(s)| \le 0.2$. As a technique for phase extension, density modification was acceptable for test cases where the resolution was extended from 1.67 to 1.0 Å, or 2.01 to 1.21 Å, but it was not very satisfactory for a resolution enhancement from 2.5 to 1.67 Å. There appear to have been no tests of this method yet with experimental data. However, the philosophy of this technique will be met again below in the description of the the maximum entropy and likelihood procedure.

2.5.7.6. Convolution techniques

One of the first relationships ever derived for phase determination is the Sayre (1952) equation:

$$F_{\mathbf{h}} = \frac{\theta}{V} \sum_{\mathbf{k}} F_{\mathbf{k}} F_{\mathbf{h} - \mathbf{k}},$$

which is a simple convolution of phased structure factors multiplied by a function of the atomic scattering factors. For structures with non-overlapping atoms, consisting of one atomic species, it is an exact expression. Although the convolution term resembles part of the tangent formula above, no statistical averaging is implied (Sayre, 1980). In X-ray crystallography this relationship has not been used very often, despite its accuracy. Part of the reason for this is that it requires relatively high resolution data for it to be useful. It can also fail for structures comprised of different atomic species.

Since, relative to X-ray scattering factors, electron scattering factors span a narrower range of magnitudes at $\sin \theta / \lambda = 0$, it might be thought that the Savre equation would be particularly useful in electron crystallography. In fact, Liu et al. (1988) were able to extend phases for simulated data from copper perchlorophthalocyanine starting at the image resolution of 2 Å and reaching the 1 Å limit of an electron-diffraction data set. This analysis has been improved with a 2.4 Å basis set obtained from the Fourier transform of an electron micrograph of this material at 500 kV and extended to the 1.0 A limit of a 1200 kV electron-diffraction pattern (Dorset et al., 1995). Using the partial phase sets for zonal diffraction data from several polymers by symbolic addition (see above), the Sayre equation has been useful for extending into the whole hk0 set, often with great accuracy. The size of the basis set is critical but the connectivity to access all reflections is more so. Fan and co-workers have had considerable success with the analysis of incommensurately modulated structures. The average structure (basis set) is found by high-resolution electron microscopy and the 'superlattice' reflections, corresponding to the incommensurate modulation, are assigned phases in hyperspace by the Sayre convolution. Examples include a high T_c superconductor (Mo et al., 1992) and the mineral ankangite (Xiang et al., 1990). Phases of regular inorganic crystals have also been extended from the electron micrograph to the electron-diffraction resolution by this technique (Hu et al., 1992).

In an investigation of how direct methods might be used for phase extension in protein electron crystallography, low-resolution phases from two proteins, bacteriorhodopsin (Henderson *et al.*, 1986) and halorhodopsin (Havelka *et al.*, 1993) were extended to higher resolution with the Sayre equation (Dorset *et al.*, 1995). For the noncentrosymmetric bacteriorhodopsin *hk*0 projection a 10 Å basis set was used, whereas a 15 Å set was accepted for the centrosymmetric halorhodopsin projection. In both cases, extensions to 6 Å resolution were reasonably successful. For bacteriorhodopsin, for which data were available to 3.5 Å, problems with the extension were encountered near 5 Å, corresponding to a minimum in a plot of average intensity *versus* resolution. Suggestions were made on how a multisolution procedure might be successful beyond this point.